

SOT - 23



- 1. BASE
- 2. EMITTER
- 3. COLLECTOR

# FMMT491 TRANSISTOR (NPN)

#### **FEATURES**

Low equivalent on-resistance

### Marking:491

### MAXIMUM RATINGS(Ta=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	80	V
VCEO	Collector-Emitter Voltage	60	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
lc	Collector Current -Continuous	1	Α
Pc	Collector Power Dissipation	250	mW
Tj	Junction Temperature	150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature	-55-150	°C

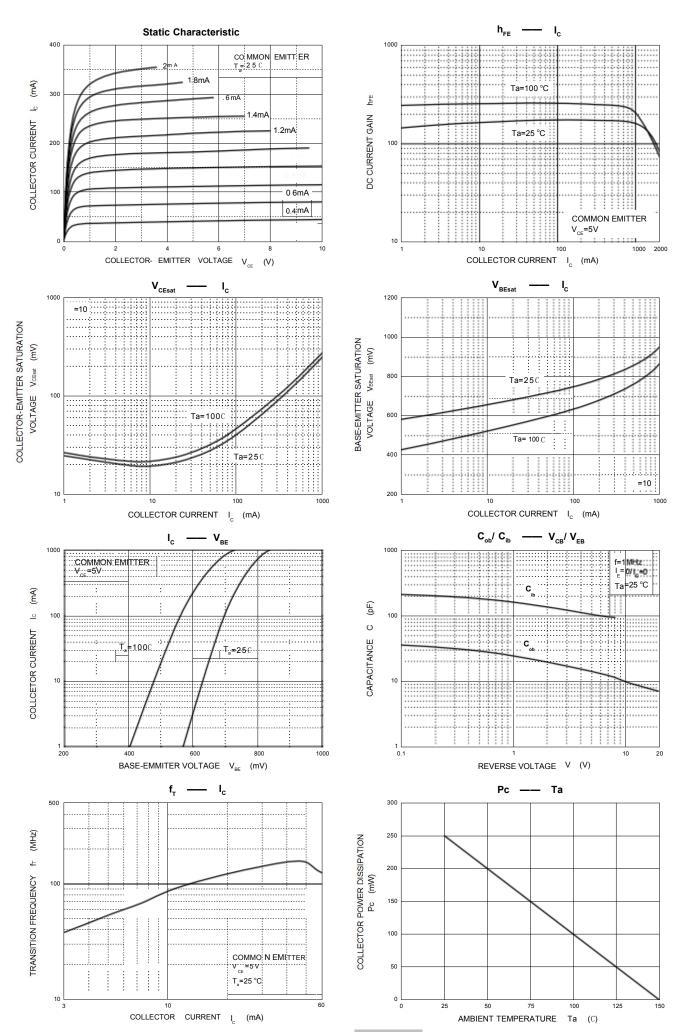
### **ELECTRICAL CHARACTERISTICS (Ta=25℃ unless otherwise specified)**

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =100pA,I <sub>E</sub> =0	80			٧
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub> <sup>1</sup>	I <sub>C</sub> =10mA,I <sub>B</sub> =0	60			٧
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =100pA,I <sub>C</sub> =0	5			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =60V,I <sub>E</sub> =0			0.1	PA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =4V,I <sub>C</sub> =0			0.1	PA
	h <sub>FE(1)</sub>	V <sub>CE</sub> =5V,I <sub>C</sub> =1mA	100			
DC ourrent goin	h <sub>FE(2)</sub> 1	V <sub>CE</sub> =5V,I <sub>C</sub> =500mA	100		300	
DC current gain	h <sub>FE(3)</sub> 1	V <sub>CE</sub> =5V,I <sub>C</sub> =1A	80			
	h <sub>FE(4)</sub> <sup>1</sup>	V <sub>CE</sub> =5V,I <sub>C</sub> =2A	30			
Collector-emitter saturation voltage	V <sub>CE(sat)1</sub> 1	I <sub>C</sub> =500mA,I <sub>B</sub> =50mA			0.25	٧
Conector-ennitier Saturation voitage	V <sub>CE(sat)2</sub> 1	I <sub>C</sub> =1A,I <sub>B</sub> =100mA			0.5	٧
Base-emitter saturation voltage	V <sub>BE(sat)</sub> <sup>1</sup>	I <sub>C</sub> =1A,I <sub>B</sub> =100mA			1.1	٧
Base-emitter voltage	V <sub>BE</sub> <sup>1</sup>	V <sub>CE</sub> =5V,I <sub>C</sub> =1A			1	V
Transition frequency	f⊤	V <sub>CE</sub> =10V,I <sub>C</sub> =50mA,,f=100MHz	150			MHz
Collector output capacitance	Cob	V <sub>CB</sub> =10V,f=1MHz			10	pF

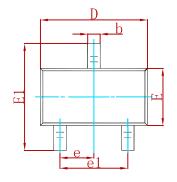
<sup>&</sup>lt;sup>1</sup>Measured under pulsed conditions, Pulse width=300 μs, Duty cycle≤2%.

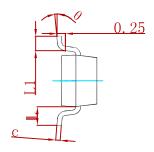


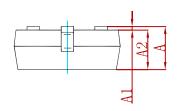




### PACKAGE MECHANICAL DATA

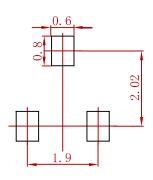






Combal	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950 TYP		0.037 TYP		
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

## Suggested Pad Layout



#### Note:

- 1.Controlling dimension:in millimeters.
- General tolerance:± 0.05mm.
- 3. The pad layout is for reference purposes only.

### **REEL SPECIFICATION**

P/N	PKG	QTY
FMMT491	SOT-23	3000





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